### **PATENT COOPERATION TREATY**

From the INTERNATIONAL SEARCHING AUTHORITY

To:					PCT
,	see form	PCT/ISA/220		INTERNATION	TEN OPINION OF THE NAL SEARCHING AUTHORITY PCT Rule 43 <i>bis</i> .1)
				Date of mailing (day/month/year) see	e form PCT/ISA/210 (second sheet)
	licant's or agent's file form PCT/ISA/2/			FOR FURTHER A See paragraph 2 below	
1	mational application I T/GB2004/00301		International filing date (	day/month/year)	Priority date (day/month/year) 12.07.2003
	rnational Patent Class 1L21/20, H01L51	• •	both national classification	and IPC	
1	licant WLETT-PACKAF	RD DEVELOPI	MENT COMPANY, L.	P.	
1.	This opinion co	ontains indication	ons relating to the foll	owing items:	
	Box No. I	Basis of the op	pinion		
	Box No. II	Priority			
	☐ Box No. III	Non-establishr	nent of opinion with reg	ard to novelty, inventiv	re step and industrial applicability
	☐ Box No. IV	Lack of unity o	f invention		
	☑ Box No. V	Reasoned stat applicability; ci	ement under Rule 43 <i>bis</i> tations and explanation	s.1(a)(i) with regard to s supporting such state	novelty, inventive step or industrial ement
	Box No. VI	Certain docum	ents cited		
	☐ Box No. VII		s in the international app		
	⊠ Box No. VIII	Certain observ	ations on the internation	nal application	
2.	FURTHER ACTI	ION			
	written opinion o the applicant cho	f the Internation ooses an Author eau under Rule	al Preliminary Examinin Ity other than this one to	g Authority ("IPEA"). He be the IPEA and the	usually be considered to be a lowever, this does not apply where chosen IPEA has notifed the tional Searching Authority
	submit to the IPE	EA a written replicate of mailing	y together, where appro	priate, with amendme	PEA, the applicant is invited to nts, before the expiration of three of 22 months from the priority date,
	For further option	ns, see Form PC	CT/ISA/220.		
3.	For further detail	s, see notes to f	Form PCT/ISA/220.		

Name and mailing address of the ISA:

**Authorized Officer** 

Pusch, C

European Patent Office D-80298 Munich Tel. +49 89 2399 - 0 Tx: 523656 epmu d Fax: +49 89 2399 - 4465

Telephone No. +49 89 2399-7023

### 10/563679

## WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

International application No. PCT/GB2004/003016

		IAP20 Res'd PCT/PTO 06 JAN 2006
_	Box N	o. I Basis of the opinion
1.		egard to the language, this opinion has been established on the basis of the international application in guage in which it was filed, unless otherwise indicated under this item.
	laı	nis opinion has been established on the basis of a translation from the original language into the following nguage , which is the language of a translation furnished for the purposes of international search nder Rules 12.3 and 23.1(b)).
2.	With renecess	egard to any nucleotide and/or amino acid sequence disclosed in the international application and sary to the claimed invention, this opinion has been established on the basis of:
	a. type	of material:
		a sequence listing
		table(s) related to the sequence listing
	b. form	nat of material:
		in written format
		in computer readable form
	c. time	of filing/furnishing:
		contained in the international application as filed.
		filed together with the international application in computer readable form.
		furnished subsequently to this Authority for the purposes of search.
3.	ha co	addition, in the case that more than one version or copy of a sequence listing and/or table relating thereto as been filed or furnished, the required statements that the information in the subsequent or additional pies is identical to that in the application as filed or does not go beyond the application as filed, as oppopriate, were furnished.
4.	Additio	onal comments:

	Box	No. il	Priority			
١.	Ø	The fol	lowing document ha	as not bee	n furnished	l:
		⊠	copy of the earlier	application	n whose pr	iority has been claimed (Rule 43bis.1 and 66.7(a)).
			translation of the e	arlier appl	ication who	se priority has been claimed (Rule 43bis.1 and 66.7(b)).
		Consec neverth	quently it has not be neless been establis	een possib shed on th	le to consi e assumpti	der the validity of the priority claim. This opinion has on that the relevant date is the claimed priority date.
<u>?</u> .		has be		ules 43 <i>bis.</i>	1 and 64.1	ity had been claimed due to the fact that the priority claim ). Thus for the purposes of this opinion, the international he relevant date.
<b>}</b> .		was no	t available to the IS	A at the ti	me that the	of the priority claim because a copy of the priority docume search was conducted (Rule 17.1). This opinion has on that the relevant date is the claimed priority date.
Į.	Add	litional c	bservations, if nece	essary:		
			·	•		
_		No. V	Reasoned state	ment und	er Rule 43	bis.1(a)(i) with regard to novelty, inventive step or
	ind	ustrial a	Reasoned state applicability; citati	ment und ons and e	er Rule 43 explanation	bis.1(a)(i) with regard to novelty, inventive step or as supporting such statement
1.	ind		Reasoned state applicability; citati	ment und ons and e	er Rule 43 explanation	bis.1(a)(i) with regard to novelty, inventive step or ns supporting such statement
1.	Stat	ustrial a	applicability; citati	ons and e	er Rule 43 explanation	bis.1(a)(l) with regard to novelty, inventive step or ns supporting such statement
1.	Stat	ustrial a	applicability; citati	ons and e	explanation	ns supporting such statement
1.	Stat Nov	ustrial a	applicability; citati	Yes: No:	explanation  Claims	ns supporting such statement
1.	Stat Nov	ement velty (N)	applicability; citati	Yes: No:	Claims Claims	1-26
1.	Stat Nov	entive st	applicability; citati	Yes: No: Yes: No:	Claims Claims Claims	1-26 13-21
1.	Stat Nov	entive st	epplicability; citati	Yes: No: Yes: No:	Claims Claims Claims Claims Claims	1-26 13-21 1-12,22-26
	Star Nov Inve	ement (N) entive st	epplicability; citati	Yes: No: Yes: No: Yes: Yes:	Claims Claims Claims Claims Claims Claims	1-26 13-21 1-12,22-26
	State Nove Inde	tement velty (N) entive startial a	epplicability; citati ep (IS) pplicability (IA)	Yes: No: Yes: No: Yes: Yes:	Claims Claims Claims Claims Claims Claims	1-26 13-21 1-12,22-26

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

see separate sheet

# WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY (SEPARATE SHEET)

IAP29 Res' International application No. 2006 PCT/GB2004/003016

### Re Item V.

1.0 The following document is referred to in this communication:

D1: US 2002/0008464, 24 January 2002

D2: US 2002/0172887, 21 November 2002

D3: WO 01/95384, 13 December 2001

D4: US 2002/0093017, 18 July 2002

D5: JP63299297, 6 December 1988

D6: US 2002/0146893, 10 October 2002

2.0 The present application does not meet the criteria of Article 33(1) PCT, because the subject-matter of claims 1 - 12, 25 and 26 does not involve an inventive step in the sense of Article 33(3) PCT.

2.1 The document D1 discloses (the references in parentheses applying to this document):

a transistor device (fig. 1) having a metallic source electrode, a metallic drain electrode, a metallic gate electrode (paragraph [0034]) and a channel in a deposited semiconductor material ("13" in fig. 1), the transistor device comprising: a first layer comprising the metallic gate electrode, a first metal portion of the metallic source electrode and a first metal portion of the metallic drain electrode; a second layer comprising a second metal portion of the metallic source electrode ("105"), a second metal portion of the metallic drain electrode ("104") the deposited semiconductor material; and

a third layer comprising a substrate ("10" in fig.1), wherein the first, second and third layers are arranged in order such that the second layer is positioned between the first layer and the third layer

from which the subject-matter of claim 1 differs in that there is a dielectric material between the semiconductor material and the metallic gate electrode. The inclusion of a gate dielectric is common practice for thin film transistors and therefore not inventive.

The subject-matter of claim 1 is not inventive.

- 2.2 Each of D2 (paragraphs [0091] [0095]) and figures 5A-5D and 6A-6D) or D3 (p. 8, l. 6 l. 15 and fig. 7) describes the transistor device of claim 1, however, the first layer is positioned between the second and the third layer. A device with poly-Si electrodes, in which the second layer lies between the first and the third layer is known from D4 (fig. 1(e)). Turning the transistor devices of D2 or D3 upside down is not inventive.
- 2.3 Dependent device claims 2 12 and device claims 25 and 26 do not do not contain any features which, in combination with the features of any claim to which they refer, meet the requirements of the PCT in respect of inventive step.
- 3.0 D5 is considered the closest prior art for method claim 13 and describes a method for use in forming a transistor device comprising:
  - (I) forming a transfer layer ("6" and "7" first figure) on a conductive carrier ("2");
  - (ii) fixing the transfer layer to a substrate (5th figure);
  - (iii) removing the conductive carrier (6th figure), wherein the transfer layer is formed in step (I) by:
  - a) selectively masking the conductive carrier ("7" first figure) to expose first, second and third portions of the conductive carrier;
  - b) electro-depositing metal onto the first, second and third portions of the conductive carrier to form first, second and third metal portions ("6");

from which the subject-matter of claim 13 differs in that further

- c) dielectric material is deposited over at least the second metal portion;
- d) metal is electro-deposited on the first and third metal portions; and
- e) semiconductor material is deposited over the dielectric layer.

It is known from D6 (paragraphs [0360] - [0364] figures 31 - 34) to transfer an entire transistor device, however the steps c) - e) are not described in D6.

The subject-matter of method claim 13 is new and inventive.

3.1 Method claims 14 - 21 being dependent on claim 13 also fulfill the requirements of PCT regarding novelty and inventive step.

#### Re Item VIII.

- 4.1 A device cannot be rendered new or inventive by the method of its manufacture, even if this method is new and inventive. A device must be described by features directly discernable in the final device which render the device as such new and inventive.
  - The feature of electrodeposited electrodes in claims 2, 25, and 26 therefore lacks clarity as does the feature of the deposited semiconductor material in claim 7 " comprising indications that it was deposited from liquid".
- 4.2 Although claims 1 and 25 have been drafted as separate independent claims, they appear to relate effectively to the same subject-matter and to differ from each other only with regard to the definition of the subject-matter for which protection is sought and in respect of the terminology used for the features of that subject-matter. The aforementioned claims therefore lack conciseness and as such do not meet the requirements of Article 6 PCT. As claim 25 comprises all the features of claim 1 it should be formulated to be dependent on claim 1.
- 4.3 The scope of protection is not clear from claims 22 24 as such, contrary to Rule 6.2(a) PCT.
  - Furthermore, the category of device claim 22 is not clear as it depends on method claims 13 21.